

Table 3. Pin Description (continued)

N°	Pin	Name	Function
4	5, 6	OUT	Stepdown regulator output
5	11	V _{CC}	Unregulated DC input voltage
6	12	BOOT	A capacitor connected between this pin and OUT allows to drive the internal DMOS Transistors
7	13	COMP	E/A output to be used for frequency compensation
8	14	FB	Stepdown feedback input. Connecting directly to this pin results in an output voltage of 3.3V. An external resistive divider is required for higher output voltages.

(*) Pins 1, 7, 8, 9, 10, 15 and 16 are not internally, electrically connected to the die.

Table 4. Thermal Data

Symbol	Parameter	Minidip	SO16	Unit
R _{th(j-amb)}	Thermal Resistance Junction to ambient	Max. 90 (*)	110 (*)	°C/W

(*) Package mounted on board.

Table 5. Absolute Maximum Ratings

Symbol		Parameter	Value	Unit
Minidip	SO16			
V ₅	V ₁₁	Input voltage	58	V
V ₄	V ₅ , V ₆	Output DC voltage Output peak voltage at t = 0.1ms f=200KHz	-1 -5	V V
I ₄	I ₅ , I ₆	Maximum output current	int. limit.	
V ₆ -V ₅	V ₁₂ -V ₁₁		14	V
V ₆	V ₁₂	Bootstrap voltage	70	V
V ₇	V ₁₃	Analogs input voltage (V _{CC} = 24V)	12	V
V ₂	V ₃	Analogs input voltage (V _{CC} = 24V)	13	V
V ₈	V ₁₄	(V _{CC} = 20V)	6 -0.3	V V
P _{tot}		Power dissipation a Tamb ≤ 60°C	DIP-8 SO16 1 0.8	W W
T _j , T _{stg}		Junction and storage temperature	-40 to 150	°C

Table 6. Electrical Characteristics

($T_j = 25^\circ\text{C}$, $C_{\text{OSC}} = 2.7\text{nF}$, $R_{\text{OSC}} = 20\text{k}\Omega$, $V_{\text{CC}} = 24\text{V}$, unless otherwise specified). "●" Specification Referred to T_j from 0 to 125°C

Symbol	Parameter	Test Condition		Min.	Typ.	Max.	Unit
DYNAMIC CHARACTERISTIC							
V _I	Operating input voltage range	V _O = 3.3 to 50V; I _O = 2A	●	8		55	V
V _O	Output voltage	I _O = 0.5A		3.33	3.36	3.39	V
		I _O = 0.2 to 2A		3.292	3.36	3.427	V
		V _{CC} = 8 to 55V	●	3.22	3.36	3.5	V
V _d	Dropout voltage	V _{CC} = 10V; I _O = 2A			0.58	0.733	V
			●			1.173	V
I _l	Maximum limiting current	V _{CC} = 8 to 55V	●	2.5	3	3.5	A
	Efficiency	V _O = 3.3V; I _O = 2A			87		%
f _s	Switching frequency		●	90	100	110	KHz
SVRR	Supply voltage ripple rejection	V _I = V _{CC} +2V _{RMS} ; V _O = V _{ref} ; I _O = 2.5A; f _{ripple} = 100Hz		60			dB
	Switching Frequency Stability vs. V _{CC}	V _{CC} = 8 to 55V			3	6	%
	Temp. stability of switching frequency	T _j = 0 to 125°C			4		%
SOFT START							
	Soft start charge current			30	40	50	μA
	Soft start discharge current			6	10	14	μA
INHIBIT							
V _{LL}	Low level voltage		●			0.9	V
I _{sLL}	Isorce Low level		●		5	15	μA
DC CHARACTERISTICS							
I _{qop}	Total operating quiescent current				4	6	mA
I _q	Quiescent current	Duty Cycle = 0; VFB= 3.8V			2.5	3.5	mA
I _{qst-by}	Total stand-by quiescent current	V _{inh} < 0.9V			100	200	μA
		V _{CC} = 55V; V _{inh} <0.9V			150	300	μA
ERROR AMPLIFIER							
V _{FB}	Voltage Feedback Input			3.33	3.36	3.39	V
R _L	Line regulation	V _{CC} = 8 to 55V			5	10	mV
	Ref. voltage stability vs temperature		●		0.4		mV/°C
V _O H	High level output voltage	V _{FB} = 2.5V		10.3			V
V _O L	Low level output voltage	V _{FB} = 3.8V				0.65	V
I _O source	Source output current	V _{comp} = 6V; V _{FB} = 2.5V		180	220		μA
I _O sink	Sink output current	V _{comp} = 6V; V _{FB} = 3.8V		200	300		μA
I _b	Source bias current				2	3	μA
SVRR E/A	Supply voltage ripple rejection	V _{comp} = V _{FB} ; V _{CC} = 8 to 55V		60	80		dB
	DC open loop gain	R _L = ∞		50	57		dB
g _m	Transconductance	I _{comp} = -0.1 to 0.1mA V _{comp} = 6V			2.5		mS

Table 6. Electrical Characteristics

($T_j = 25^{\circ}\text{C}$, $C_{\text{OSC}} = 2.7\text{nF}$, $R_{\text{OSC}} = 20\text{k}\Omega$, $V_{\text{CC}} = 24\text{V}$, unless otherwise specified). "●" Specification Referred to T_j from 0 to 125°C

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
OSCILLATOR SECTION						
	Ramp Valley		0.78	0.85	0.92	V
	Ramp peak	$V_{\text{CC}} = 8\text{V}$	2	2.15	2.3	V
		$V_{\text{CC}} = 55\text{V}$	9	9.6	10.2	V
	Maximum duty cycle		95	97		%
	Maximum Frequency	Duty Cycle = 0% $R_{\text{OSC}} = 13\text{k}\Omega$, $C_{\text{OSC}} = 820\text{pF}$			300	kHz

Figure 4. Test and evaluation board circuit.

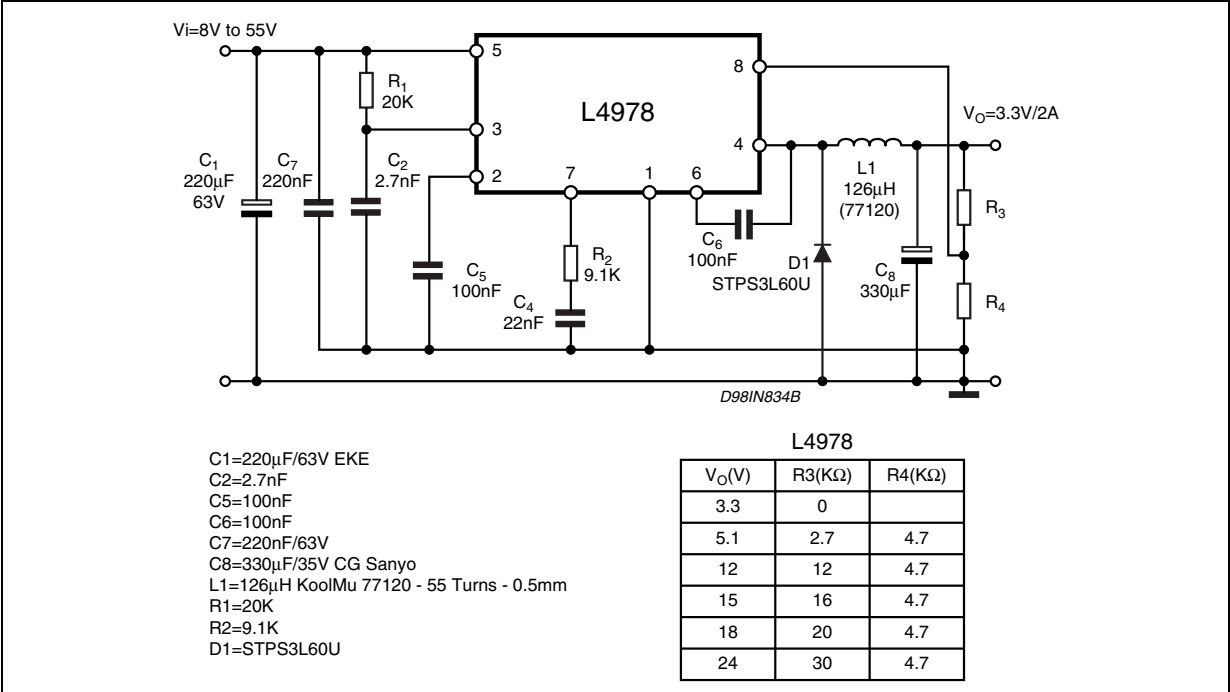


Figure 5. PCB and component layout of the figure 4.

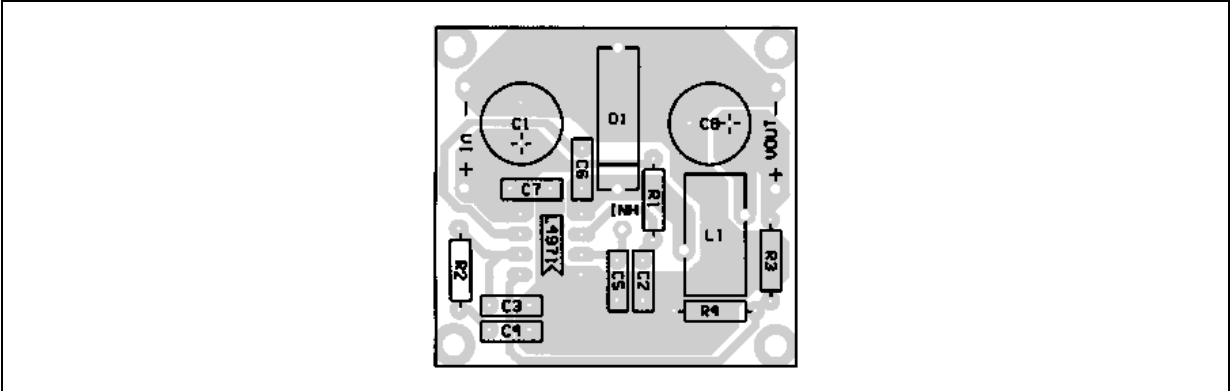


Figure 6. Quiescent drain current vs. input voltage.

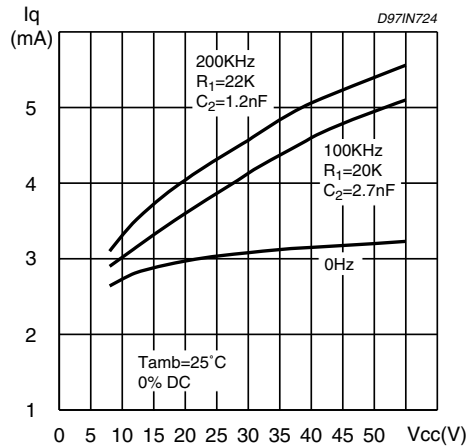


Figure 7. Quiescent current vs. junction temperature

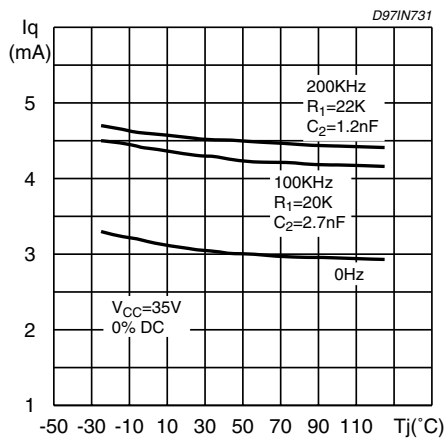


Figure 8. Stand by drain current vs. input voltage.

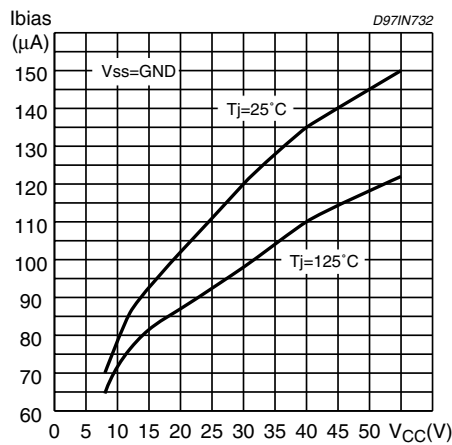


Figure 9. Line Regulation

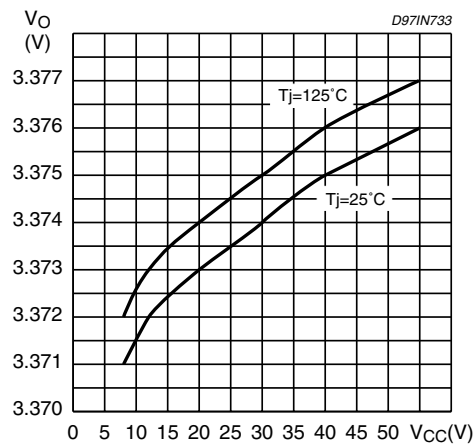


Figure 10. Load regulation

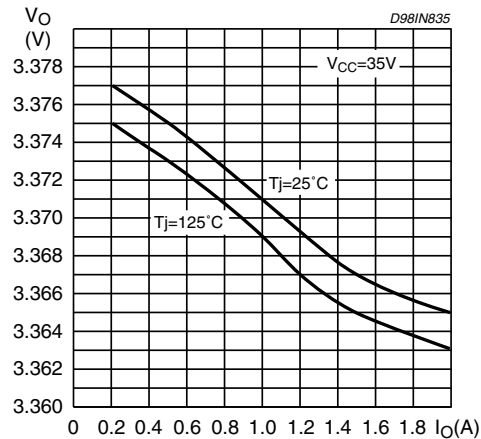


Figure 11. Switching frequency vs. R1 and C2

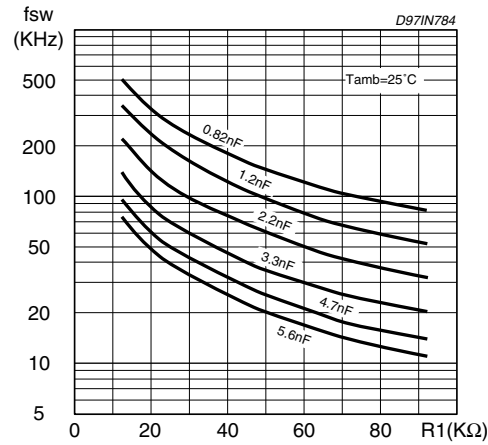


Figure 12. Switching Frequency vs. input voltage..

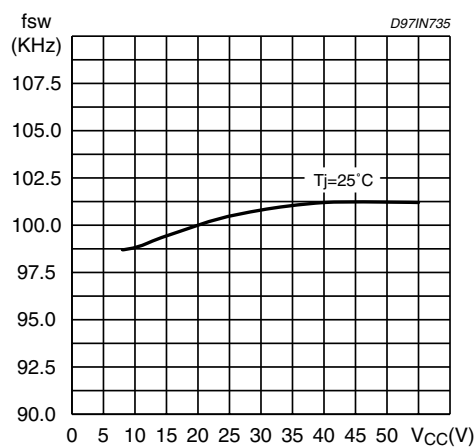


Figure 13. Switching frequency vs. junction temperature.

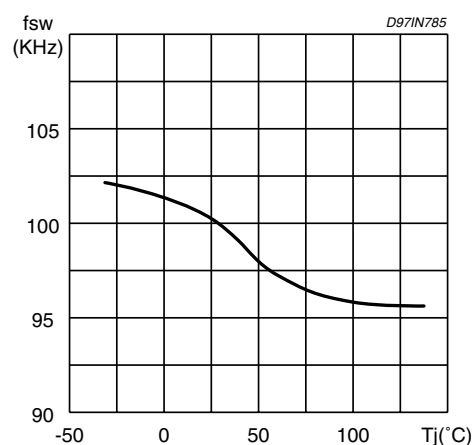


Figure 14. Dropout voltage between pin 5 and 4.

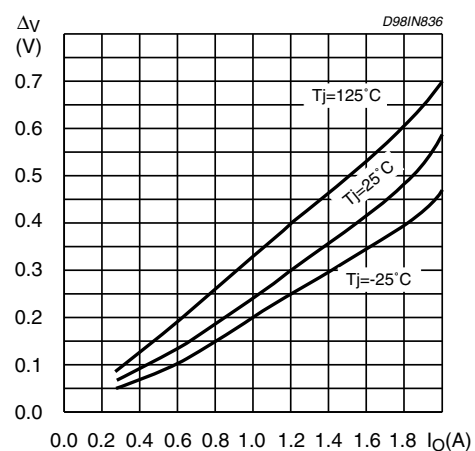


Figure 15. Efficiency vs output voltage.

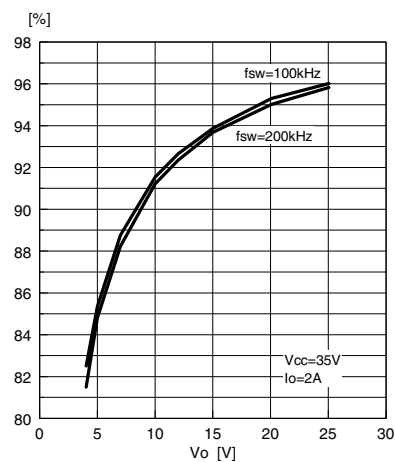


Figure 16. Efficiency vs. output current.

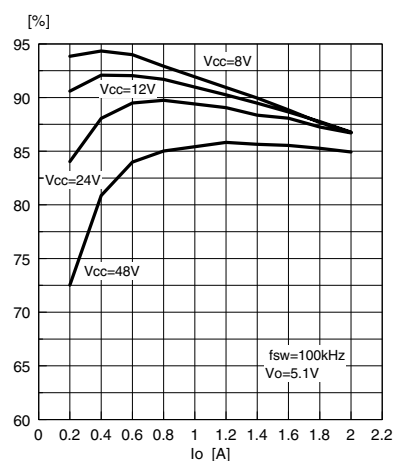


Figure 17. Efficiency vs. output current.

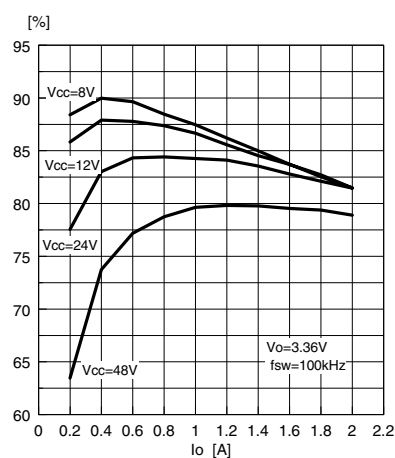


Figure 18. Efficiency vs. output current.

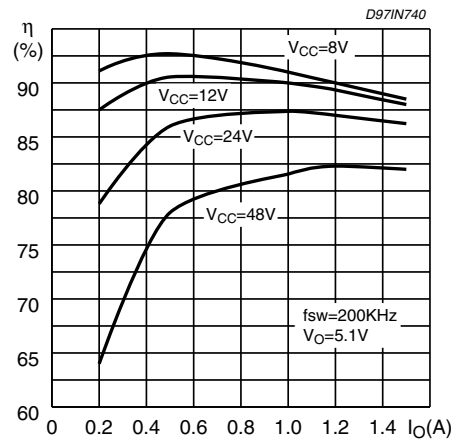


Figure 19. Efficiency vs. output current.

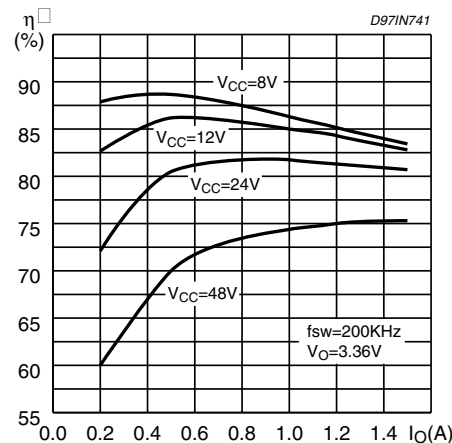


Figure 20. Efficiency vs. Vcc.

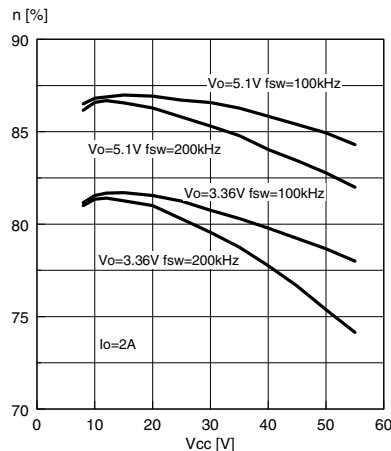


Figure 21. Power dissipation vs. Vcc.

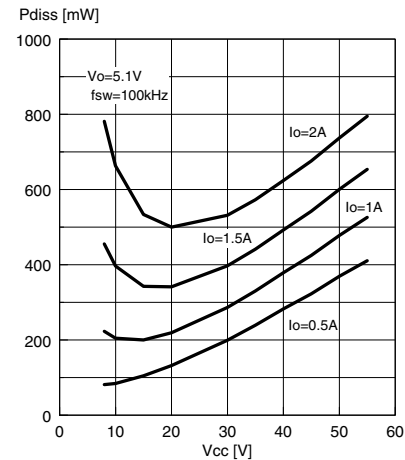


Figure 22. Device Power dissipation vs. V_O

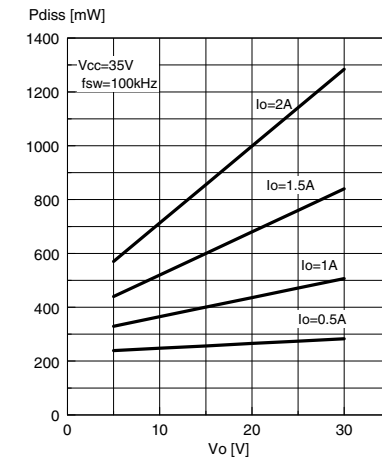


Figure 23. Pulse by pulse limiting current vs. junction temperature..

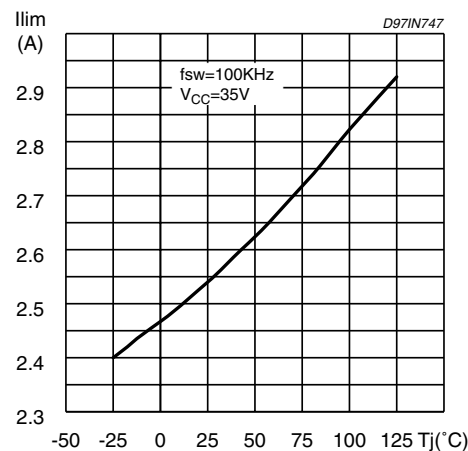


Figure 24. Load transient.

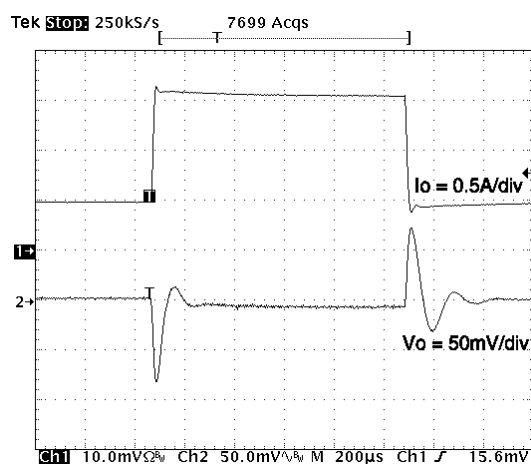


Figure 25. Line transient.

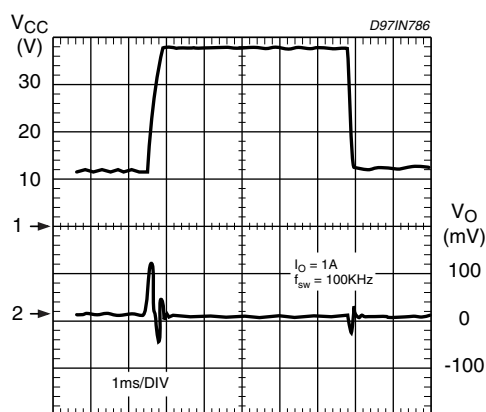
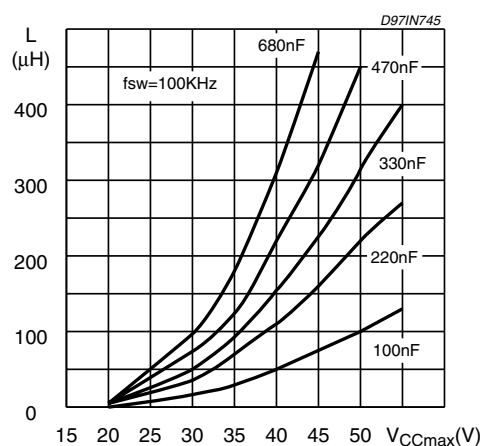
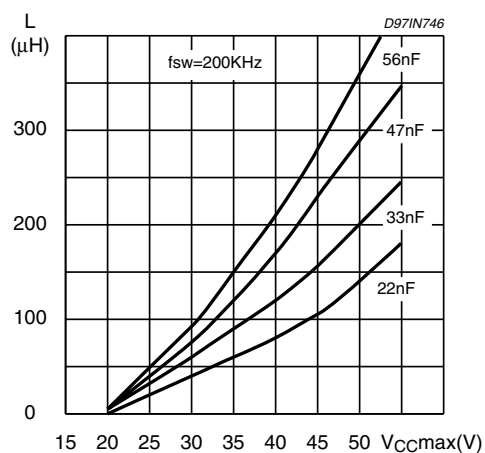
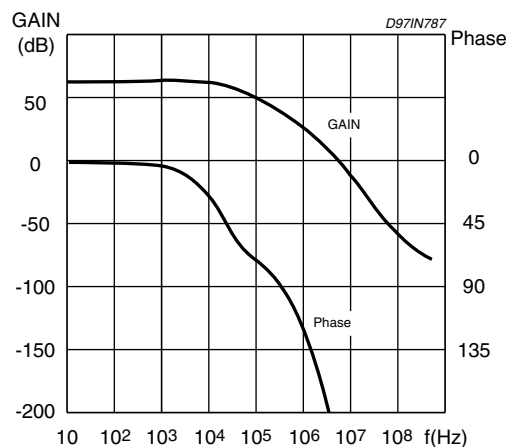
Figure 26. Soft start capacitor selection Vs inductor and V_{CCmax} .Figure 27. Soft start capacitor selection Vs inductor and V_{CCmax} .

Figure 28. Open loop frequency and phase of error amplifier.



3 Package Informations

Figure 29. DIP-8 Mechanical Data & Package Dimensions

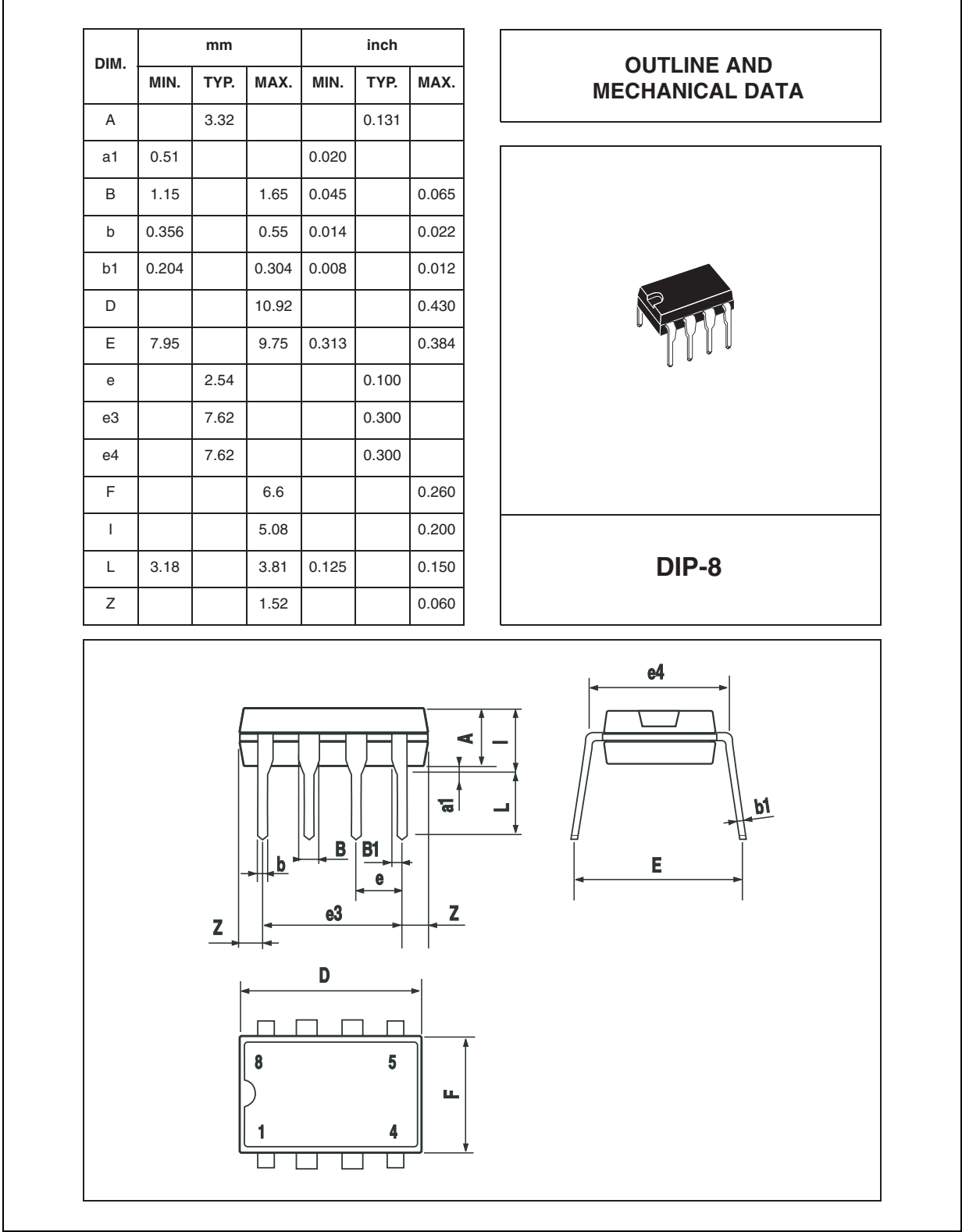
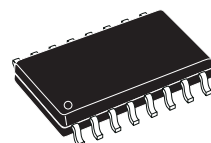


Figure 30. SO16 Wide Mechanical Data & Package Dimensions

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.35		2.65	0.093		0.104
A1	0.10		0.30	0.004		0.012
B	0.33		0.51	0.013		0.200
C	0.23		0.32	0.009		0.013
D ⁽¹⁾	10.10		10.50	0.398		0.413
E	7.40		7.60	0.291		0.299
e		1.27			0.050	
H	10.0		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

(1) "D" dimension does not include mold flash, protusions or gate burrs. Mold flash, protusions or gate burrs shall not exceed 0.15mm per side.

OUTLINE AND MECHANICAL DATA



SO16 (Wide)

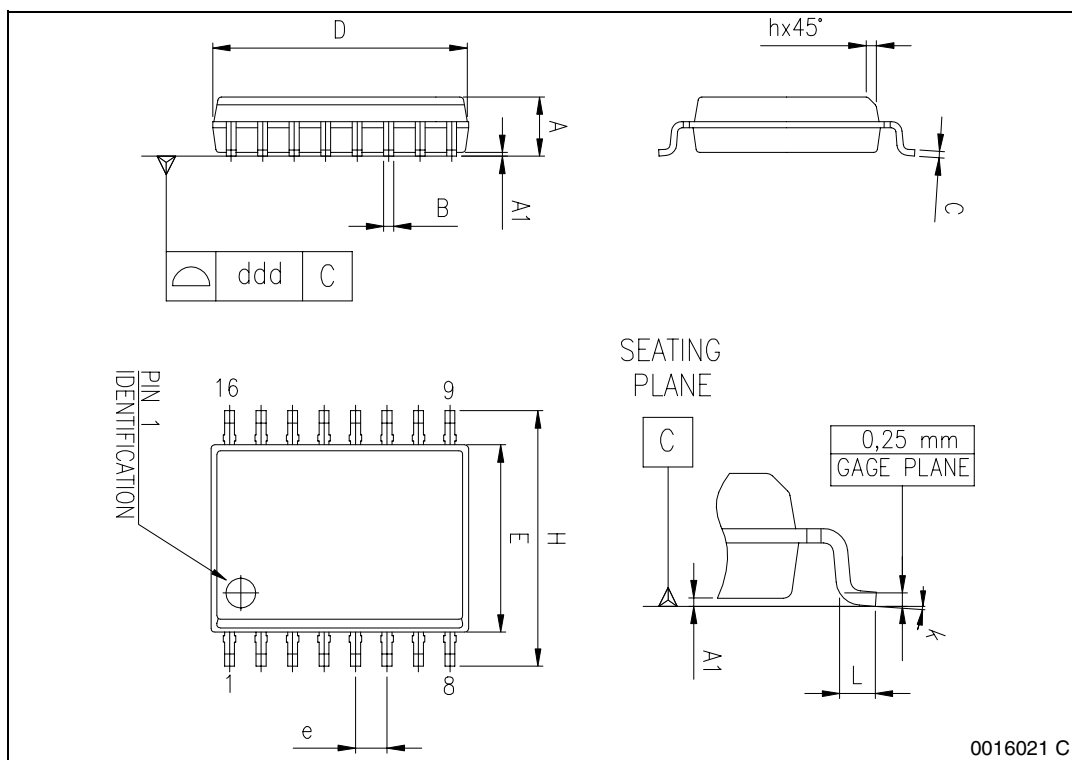


Table 7. Revision History

Date	Revision	Description of Changes
October 2001	8	First Issue
May 2005	9	Modified D1 on the Fig. 4.

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